NSN 5961-01-315-3268

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-315-3268 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 1.030 inches and 1.070 inches Overall Diameter: Between 2.850 inches and 2.900 inches **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak off-state voltage and 1000.0 repetitive peak reverse voltage and 1000.0 nonrepetitive peak off-state voltage and 1100.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 1590.00 amperes forward current, total rms horsepower metric and 1000.00 amperes forward current, total rms universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L04159; for navy nuclear propulsion plant products only **Terminal Type And Quantity:** 2 case and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0